

What is claimed is:

1 1. An active matrix type liquid crystal display device,
2 comprising:

3 a TFT substrate having a common wiring and a source/drain
4 wiring formed on a first substrate, said first substrate being
5 provided with

6 an insulating film covering said common wiring and said
7 source/drain wiring, said insulating film being coated with
8 a first alignment layer;

9 an opposite substrate opposing to said TFT substrate
10 having a second alignment layer formed on a second substrate;

11 a liquid crystal held between said first alignment layer
12 and said second alignment layer; and

13 a common electrode and a pixel electrode wired in parallel
14 with each other being formed as parts of said common wiring
15 and said source/drain wiring, respectively, so that an angle
16 made between a direction in which said first alignment layer
17 is subjected to aligning treatment and a direction in which
18 said second alignment layer is subjected to aligning treatment
19 is set to a value of 0.5 to 4.0 degrees.

1 2. The active matrix type liquid crystal display device
2 according to claim 1, wherein said angle made between said
3 direction in which said first alignment layer is subjected
4 to aligning treatment and said direction in which said second
5 alignment layer is subjected to aligning treatment is set to
6 a value of 1.5 to 2.0 degrees.

1 3. The active matrix type liquid crystal display device
2 according to claim 1, wherein said direction in which said
3 first alignment layer is subjected to aligning treatment has
4 an angle of 5 to 45 degrees with respect to a direction in
5 which said common electrode and said pixel electrode are wired
6 in parallel with each other.

1 4. The active matrix type liquid crystal display device
2 according to claim 1, wherein an angle made between a direction
3 in which said second alignment layer is subjected to aligning
4 treatment and a direction in which said common electrode and
5 said pixel electrode are wired in parallel with each other
6 is larger than an angle made between said direction in which
7 said first alignment layer is subjected to aligning treatment
8 and a direction in which said common electrode and said pixel
9 electrode are wired in parallel with each other.

1 5. The active matrix type liquid crystal display device
2 according to claim 1, wherein said TFT substrate and said
3 opposite substrate having said liquid crystal therebetween
4 include a first substrate side polarizer and a second substrate
5 side polarizer on opposite sides opposing to inner sides of
6 said TFT substrate and said opposite substrate facing said
7 liquid crystal, respectively, and in said first substrate side
8 polarizer and said second substrate side polarizer, the
9 absorption axis and transmission axis are mutually orthogonal,

10 and any one of the absorption axis and the transmission axis
11 of said first substrate side polarizer agrees with said
12 direction in which said first alignment layer is subjected
13 to aligning treatment.

1 6. The active matrix type liquid crystal display device
2 according to claim 1, wherein a distance between surfaces of
3 said first alignment layer and said second alignment layer
4 opposing to each other is set to a value of 1.0 μm to 6.0 μm .

1 7. The active matrix type liquid crystal display device
2 according to claim 1, wherein a distance between said common
3 electrode and said pixel electrode wired in parallel with each
4 other is set to a value of 2 μm to 15 μm .

1 8. The active matrix type liquid crystal display device
2 according to claim 1, wherein a gate wiring of a thin film
3 transistor is formed on said first substrate simultaneously
4 with said common wiring.

1 9. The active matrix type liquid crystal display device
2 according to claim 1, wherein an island disposed above said
3 common wiring and made of a semiconductor film is formed in
4 said insulating film, and said island constitutes an active
5 region of a thin film transistor.